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U.S. PATENT DOCUMENTS

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FOREIGN PATENT OR PUBLISHED FOREIGN PATENT APPLICATION

EXAMINER | DOCUMENT NUMBER | PUBLICATION | COUNTRY OR PATENT OFFICE | CLASS | SUB- TRANSLATION |

KR 2003 | 0 | 0 | 2 | 4 | 1 | 5 | 6 | 3/26/03 | Korea | |

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VEST | NO

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11	'Observation of the Mott Transition in VO ₂ Based Transistors', Kim, Hyun-Tak, et al. Telecom. Basic Research Lab, ETRI, Daejeon 305-350, South Korea (August		
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1	'Gate-Induced Mott Transition'. Kim, Hyun-Tak, et al. Telecom. Basic Research Lab, ETRI, Daejeon 305-350, Korea (May 27, 2003) pp. 1-4.		
EXAMINER DATE CONSIDERED 5/3 1/07			
EXAMINER: Initial citation considered. Draw line through citation if not In conformance and not considered. Include copy of this form with next communication to applicant.			

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